# MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED

**BAS321** 

## Product specification

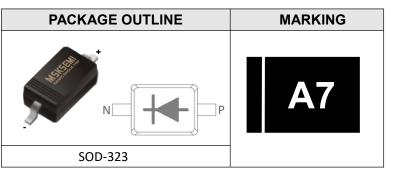




### **FEATURES**

- FastSwitchingSpeed:max.50nS.
- ContinuousReverseVoltage:max.200V.
- LowLeakageCurrent:100nAatRoomTemperature.
- SurfaceMountPackageIdeallySuitedforAutomaticI nsertion.

#### **Reference News**



## Absolute Maximum Ratings(Ta=25℃)

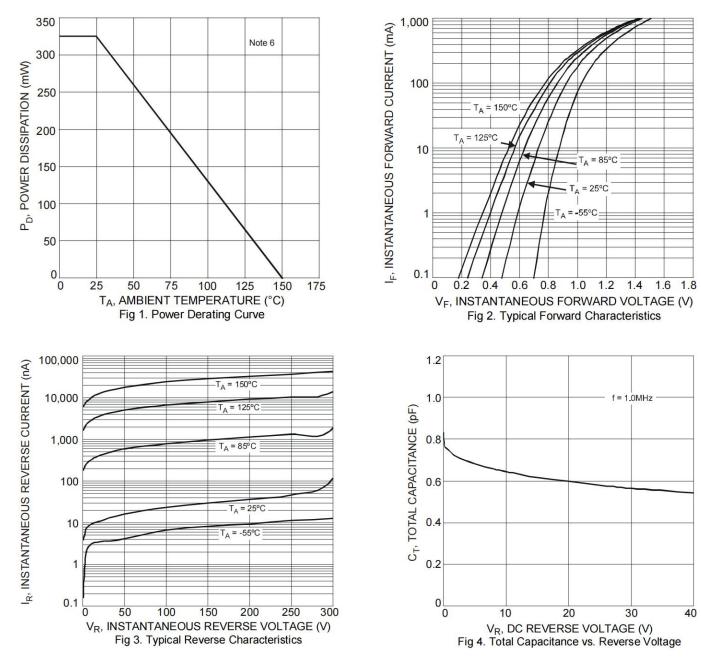
Symbol	Parameter	Value	Unit
Vrm	Non-repetitive Peak Reverse Voltage	250	V
Vrrm	Peak Repetitive Peak Reverse Voltage		
VRWM	Working Peak Reverse Voltage	200	V
VR	DC Blocking Voltage		
Iгм	Forward Continuous Current(Note 1)	250	mA
IFSM	Non-repetitive Peak Forward Surge Current@t=1µS	4.5	A
FRM	Repetitive Peak Forward Current(Note 1)	1	A
Pd	Power Dissipation(Note 1)	325	mW
Roja	Thermal Resistance From Junction To Ambient(Note 1)	385	°C/W
TJ	Operation Junction Temperature Range	-40~+150	°C
Tstg	Storage Temperature Range	-55~+150	°C

## Electrical Characteristics (Ta=25°C unless otherwise specified)

Symbol	Parameter	Test conditions	Min	Тур	Мах	Unit
V <sub>(BR)</sub>	Reverse breakdown voltage(Note 2)	l <sub>R</sub> =100µA	250			V
lĸ	Reverse current(Note 2)	V <sub>R</sub> =200V			100	nA
		V <sub>R</sub> =200V,TJ=150℃			100	μA
VF	Forward voltage	l⊧=100mA			1.1	V
		l <sub>F</sub> =100mA			1.25	
Ст	Capacitance Between Terminals	V <sub>R</sub> =0V, f=1MHz		5		pF
t <sub>rr</sub>	Reverse recovery time	l <sub>F</sub> =I <sub>R</sub> =30mA			50	nS
		$I_{rr}$ =0.1X $I_R$ , $R_L$ =100 $\Omega$			50	

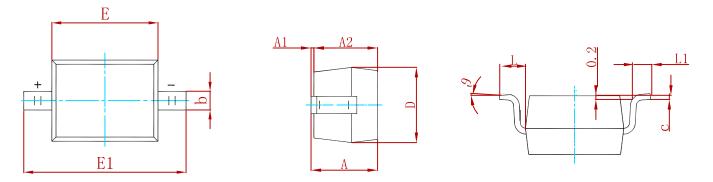


## **Typical Characteristics**



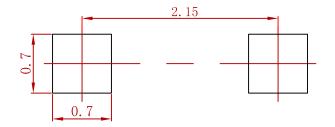


#### PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A		1.000		0.039	
A 1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
с	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.550	2.750	0.100	0.108	
L	0.475	REF.	0.019	REF.	
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

#### Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
BAS321	SOD-323	3000



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